Dual 4-Channel Data Selector/Multiplexer

MC14539B

The MC14539B data selector/multiplexer is constructed with MOS P–channel and N–channel enhancement mode devices in a single monolithic structure. The circuit consists of two sections of four inputs each. One input from each section is selected by the address inputs A and B. A "high" on the Strobe input will cause the output to remain "low".

This device finds primary application in signal multiplexing functions. It permits multiplexing from N–lines to I–line, and can also perform parallel–to–serial conversion. The Strobe input allows cascading of n–lines to n–lines.

- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low–Power TTL Loads or One Low–Power Schottky TTL Load Over the Rated Temperature Range

L SUFFIX
CERAMIC
CASE 620

P SUFFIX
PLASTIC
CASE 648
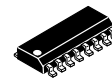
D SUFFIX
SOIC
CASE 751B

ORDERING INFORMATION

MC14XXXBCP	Plastic
MC14XXXBCL	Ceramic
MC14XXXBD	SOIC

$T_A = -55°$ to $125°C$ for all packages.

MAXIMUM RATINGS* (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage	-0.5 to $+18.0$	V
V_{in}, V_{out}	Input or Output Voltage (DC or Transient)	-0.5 to $V_{DD} + 0.5$	V
I_{in}, I_{out}	Input or Output Current (DC or Transient), per Pin	± 10	mA
P_D	Power Dissipation, per Package†	500	mW
T_{stg}	Storage Temperature	-65 to $+150$	°C
T_L	Lead Temperature (8–Second Soldering)	260	°C

* Maximum Ratings are those values beyond which damage to the device may occur.
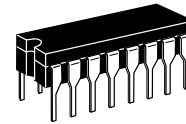†Temperature Derating:
    Plastic "P and D/DW" Packages: -7.0 mW/°C From 65°C To 125°C
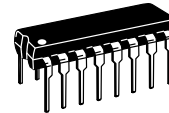   Ceramic "L" Packages: -12 mW/°C From 100°C To 125°C

TRUTH TABLE

Address Inputs		Data Inputs					Outputs
B	A	X3 Y3	X2 Y2	X1 Y1	X0 Y0	ST, ST′	Z, W
X	X	X	X	X	X	1	0
0	0	X	X	X	0	0	0
0	0	X	X	X	1	0	1
0	1	X	X	0	X	0	0
0	1	X	X	1	X	0	1
1	0	X	0	X	X	0	0
1	0	X	1	X	X	0	1
1	1	0	X	X	X	0	0
1	1	1	X	X	X	0	1

X = Don't Care

BLOCK DIAGRAM

V_{DD} = PIN 16
V_{SS} = PIN 8

MOTOROLA

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic	Symbol	V_{DD} Vdc	−55°C Min	−55°C Max	25°C Min	25°C Typ #	25°C Max	125°C Min	125°C Max	Unit
Output Voltage "0" Level $V_{in} = V_{DD}$ or 0	V_{OL}	5.0	—	0.05	—	0	0.05	—	0.05	Vdc
		10	—	0.05	—	0	0.05	—	0.05	
		15	—	0.05	—	0	0.05	—	0.05	
"1" Level $V_{in} = 0$ or V_{DD}	V_{OH}	5.0	4.95	—	4.95	5.0	—	4.95	—	Vdc
		10	9.95	—	9.95	10	—	9.95	—	
		15	14.95	—	14.95	15	—	14.95	—	
Input Voltage "0" Level (V_O = 4.5 or 0.5 Vdc) (V_O = 9.0 or 1.0 Vdc) (V_O = 13.5 or 1.5 Vdc)	V_{IL}	5.0	—	1.5	—	2.25	1.5	—	1.5	Vdc
		10	—	3.0	—	4.50	3.0	—	3.0	
		15	—	4.0	—	6.75	4.0	—	4.0	
"1" Level (V_O = 0.5 or 4.5 Vdc) (V_O = 1.0 or 9.0 Vdc) (V_O = 1.5 or 13.5 Vdc)	V_{IH}	5.0	3.5	—	3.5	2.75	—	3.5	—	Vdc
		10	7.0	—	7.0	5.50	—	7.0	—	
		15	11	—	11	8.25	—	11	—	
Output Drive Current (V_{OH} = 2.5 Vdc) Source (V_{OH} = 4.6 Vdc) (V_{OH} = 9.5 Vdc) (V_{OH} = 13.5 Vdc)	I_{OH}	5.0	− 3.0	—	− 2.4	− 4.2	—	− 1.7	—	mAdc
		5.0	− 0.64	—	− 0.51	− 0.88	—	− 0.36	—	
		10	− 1.6	—	− 1.3	− 2.25	—	− 0.9	—	
		15	− 4.2	—	− 3.4	− 8.8	—	− 2.4	—	
(V_{OL} = 0.4 Vdc) Sink (V_{OL} = 0.5 Vdc) (V_{OL} = 1.5 Vdc)	I_{OL}	5.0	0.64	—	0.51	0.88	—	0.36	—	mAdc
		10	1.6	—	1.3	2.25	—	0.9	—	
		15	4.2	—	3.4	8.8	—	2.4	—	
Input Current	I_{in}	15	—	±0.1	—	±0.00001	±0.1	—	±1.0	µAdc
Input Capacitance ($V_{in} = 0$)	C_{in}	—	—	—	—	5.0	7.5	—	—	pF
Quiescent Current (Per Package)	I_{DD}	5.0	—	5.0	—	0.005	5.0	—	150	µAdc
		10	—	10	—	0.010	10	—	300	
		15	—	20	—	0.015	20	—	600	
Total Supply Current**† (Dynamic plus Quiescent, Per Package) (C_L = 50 pF on all outputs, all buffers switching)	I_T	5.0 10 15	\multicolumn{7}{c}{$I_T = (0.85 \text{ µA/kHz}) \text{ f} + I_{DD}$ $I_T = (1.70 \text{ µA/kHz}) \text{ f} + I_{DD}$ $I_T = (2.60 \text{ µA/kHz}) \text{ f} + I_{DD}$}	µAdc

\#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

** The formulas given are for the typical characteristics only at 25°C.

†To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

where: I_T is in µA (per package), C_L in pF, V = ($V_{DD} - V_{SS}$) in volts, f in kHz is input frequency, and k = 0.002.

> This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in}$ or $V_{out}) \leq V_{DD}$.
> Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

SWITCHING CHARACTERISTICS* (C_L = 50 pF, T_A = 25°C)

Characteristic	Symbol	V_{DD}	Min	Typ #	Max	Unit
Output Rise and Fall Time	t_{TLH}, t_{THL}					ns
$\quad t_{TLH}$, t_{THL} = (1.5 ns/pF) C_L + 25 ns		5.0	—	100	200	
$\quad t_{TLH}$, t_{THL} = (0.75 ns/pF) C_L + 12.5 ns		10	—	50	100	
$\quad t_{TLH}$, t_{THL} = (0.55 ns/pF) C_L + 9.5 ns		15	—	40	80	
Propagation Delay Time	t_{PLH}, t_{PHL}					ns
$\quad$ X, Y Input to Output						
$\quad t_{PLH}$, t_{PHL} = (1.7 ns/pF) C_L + 125 ns		5.0	—	210	420	
$\quad t_{PLH}$, t_{PHL} = (0.66 ns/pF) C_L + 57 ns		10	—	90	180	
$\quad t_{PLH}$, t_{PHL} = (0.55 ns/pF) C_L + 45 ns		15	—	70	140	
$\quad$ A Input to Output	t_{PLH}					ns
$\quad t_{PLH}$ = (1.7 ns/pF) C_L + 140 ns		5.0	—	225	450	
$\quad t_{PLH}$ = (0.66 ns/pF) C_L + 77 ns		10	—	110	220	
$\quad t_{PLH}$ = (0.5 ns/pF) C_L + 60 ns		15	—	85	170	
$\quad t_{PHL}$ = (1.7 ns/pF) C_L + 160 ns	t_{PHL}	5.0	—	245	490	ns
$\quad t_{PHL}$ = (0.66 ns/pF) C_L + 82 ns		10	—	115	230	
$\quad t_{PHL}$ = (0.5 ns/pF) C_L + 65 ns		15	—	90	180	
$\quad$ Strobe Input to Output	t_{PLH}, t_{PHL}					ns
$\quad t_{PLH}$, t_{PHL} = (1.7 ns/pF) C_L + 60 ns		5.0	—	145	290	
$\quad t_{PLH}$, t_{PHL} = (0.66 ns/pF) C_L + 42 ns		10	—	75	150	
$\quad t_{PLH}$, t_{PHL} = (0.5 ns/pF) C_L + 35 ns		15	—	60	120	

* The formulas given are for the typical characteristics only at 25°C.
#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
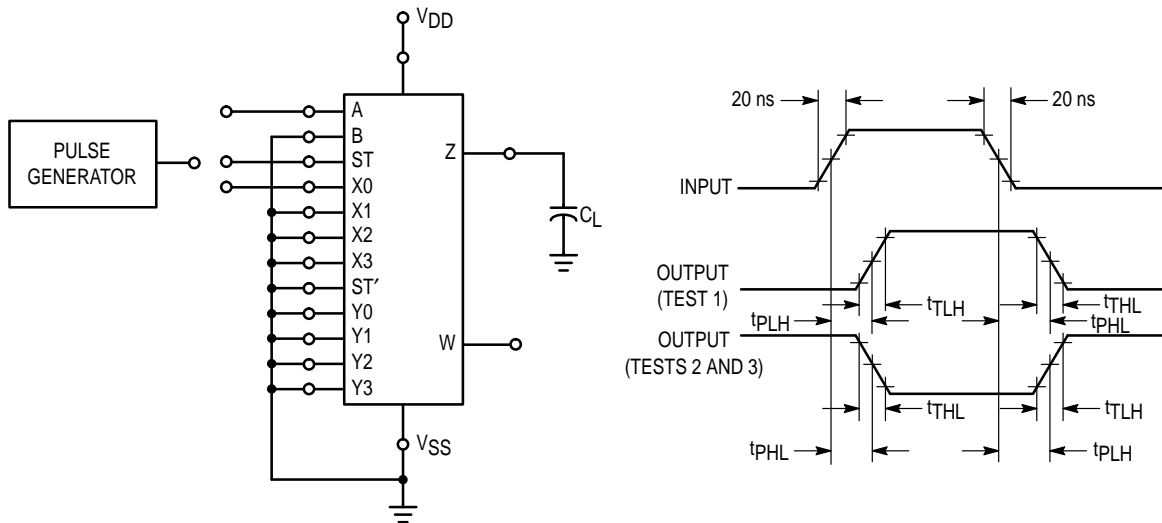
INPUT CONNECTIONS FOR t_{TLH}, t_{THL}, t_{PHL}, t_{PLH}

Test	Strobe	A	X0
1	Gnd	Gnd	P.G.
2	P.G.	Gnd	V_{DD}
3	Gnd	P.G.	V_{DD}

Figure 1. AC Test Circuit and Waveforms
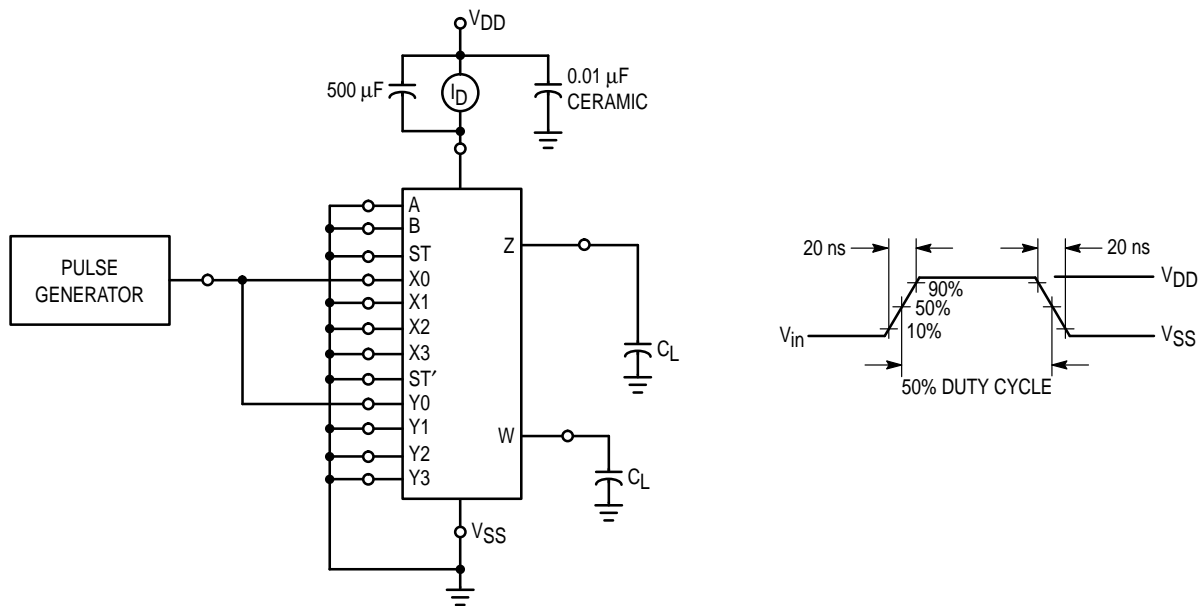
Figure 2. Power Dissipation Test Circuit and Waveform

LOGIC DIAGRAM

PIN ASSIGNMENT

ST	1 ●	16	V$_{DD}$
B	2	15	ST′
X3	3	14	A
X2	4	13	Y3
X1	5	12	Y2
X0	6	11	Y1
Z	7	10	Y0
V$_{SS}$	8	9	W
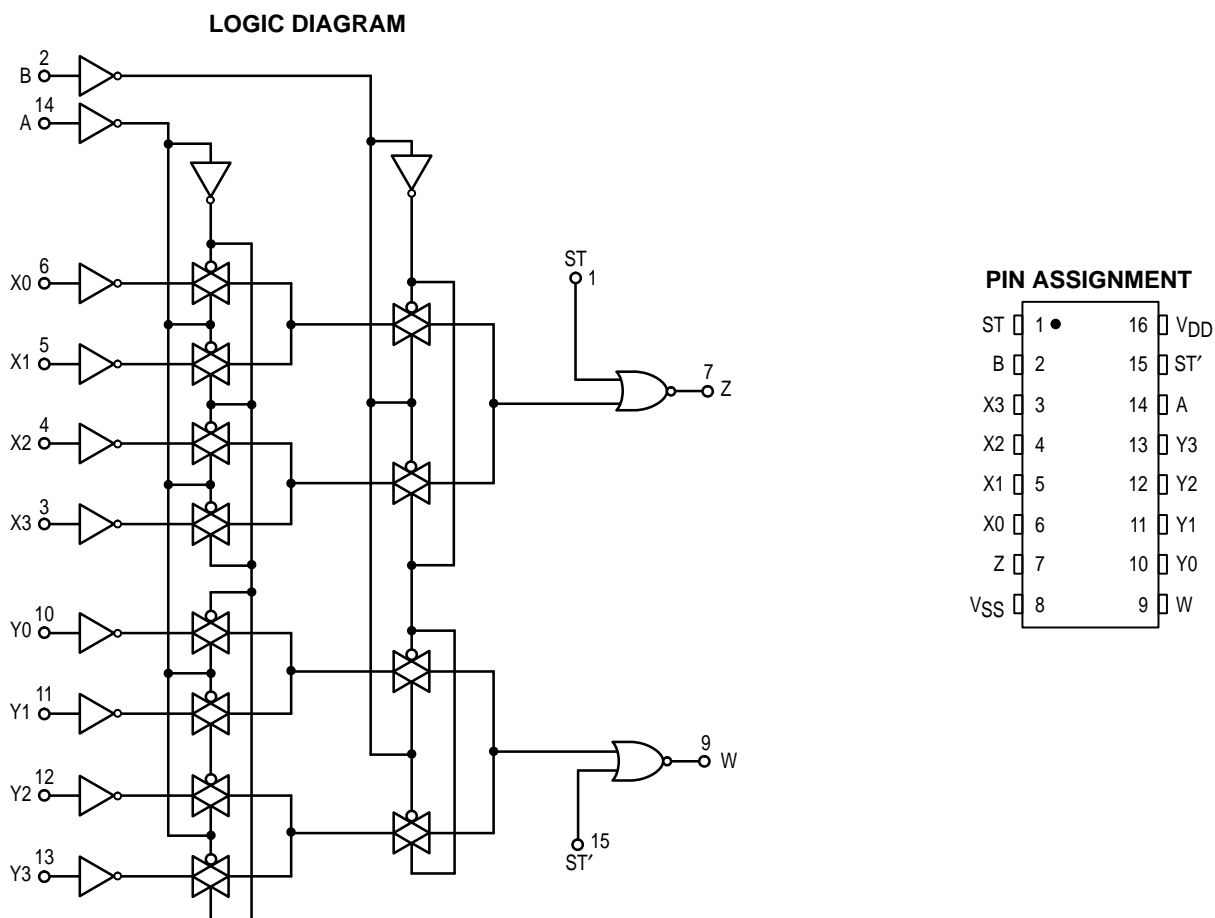
OUTLINE DIMENSIONS

L SUFFIX
CERAMIC DIP PACKAGE
CASE 620–10
ISSUE V
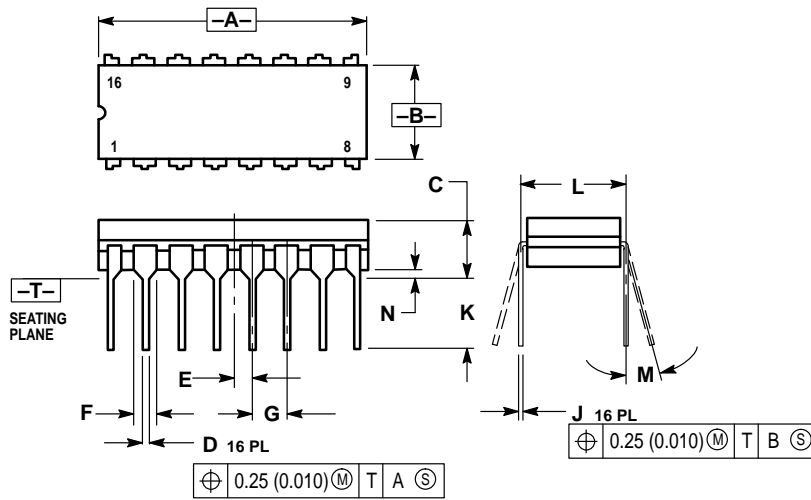
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.750	0.785	19.05	19.93
B	0.240	0.295	6.10	7.49
C	—	0.200	—	5.08
D	0.015	0.020	0.39	0.50
E	0.050 BSC		1.27 BSC	
F	0.055	0.065	1.40	1.65
G	0.100 BSC		2.54 BSC	
H	0.008	0.015	0.21	0.38
K	0.125	0.170	3.18	4.31
L	0.300 BSC		7.62 BSC	
M	0 °	15 °	0 °	15 °
N	0.020	0.040	0.51	1.01

P SUFFIX
PLASTIC DIP PACKAGE
CASE 648–08
ISSUE R
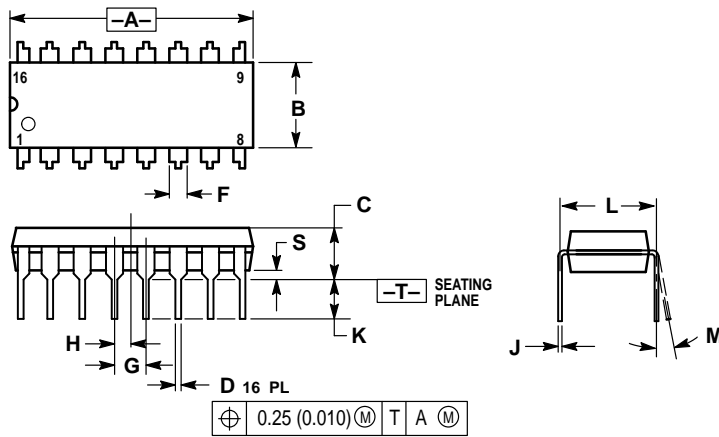
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0 °	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

OUTLINE DIMENSIONS

D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751B–05
ISSUE J
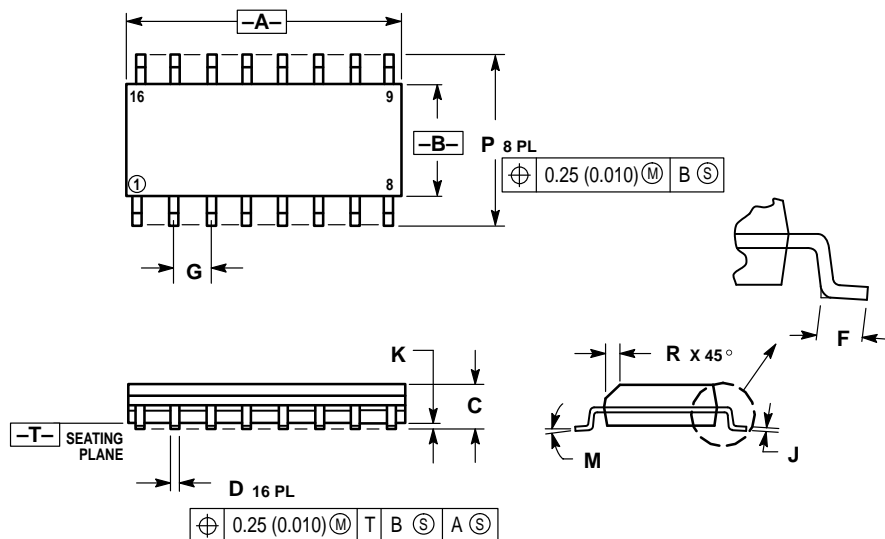
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

MOTOROLA

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MC14539B/D